Lattice Semiconductor Corporation - ICE40LM4K-SWG25TR50 Datasheet

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Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Discontinued at Digi-Key
Number of LABs/CLBs	440
Number of Logic Elements/Cells	3520
Total RAM Bits	81920
Number of I/O	18
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	25-XFBGA, WLCSP
Supplier Device Package	25-WLCSP (1.7x1.7)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/ice40lm4k-swg25tr50

iCE40LM Family Data Sheet Introduction

October 2013 **Advance Data Sheet DS1045**

General Description

iCE40LM family is an ultra-low power FPGA and sensor manager designed for ultra-low power mobile applications, such as smartphones, tablets and hand-held devices. The iCE40LM family includes integrated SPI & I^{2}C blocks to interface with virtually all mobile sensors and application processors. The iCE40LM family also features two Strobe Generators that can generates strobes in Microsecond ranges with the Low-Power Strobe Generator, and also generates strobes in Nanosecond ranges with the High-Speed Strobe Generator.

In addition, the iCE40LM family of devices includes logic to perform other functions such as mobile bridging, antenna tuning, GPIO expansion, motion/gesture recognition, IR remote control, bar code emulation and other custom functions.

The iCE40LM family features three device densities, from 1000 to 3520 Look Up Tables (LUTs) of logic with programmable I/Os that can be used as either SPI/I^{2}C interface ports or general purpose I/O's. It also has up to 80Kbits of Block RAMs to work with user logic.

Features

- **Flexible Logic Architecture**
  - Three devices with 1000 to 3520 LUTs
  - 18 I/O pins for 25-pin WLCSP
- **Ultra-low Power Devices**
  - Advanced 40 nm ultra-low power process
  - As low as 120 µW standby power typical
- **Embedded and Distributed Memory**
  - Up to 80 Kbits sysMEM™ Embedded Block RAM
- **Two Hardened I^{2}C Interfaces**
- **Two Hardened SPI Interfaces**
- **Two On-Chip Strobe Generators**
  - Low-Power Strobe Generator (Microsecond ranges)
  - High-Speed Strobe Generator (Nanosecond ranges)
- **High Current Drive Outputs for LED**
  - 3 High Drive (HD) output in each device
  - Source/sink nominal 24mA
- **Flexible On-Chip Clocking**
  - Six low-skew global signal resource
- **Flexible Device Configuration**
  - SRAM is configured through SPI
- **Ultra-Small Form Factor**
  - As small as 25-pin WLCSP package 1.71mm x 1.71 mm

Applications

- Smartphones
- Tablets and Consumer Handheld Devices
- Handheld Commercial and Industrial Devices
- Multi Sensor Management Applications
- Sensor Pre-processing & Sensor Fusion
- Always-On Sensor Applications

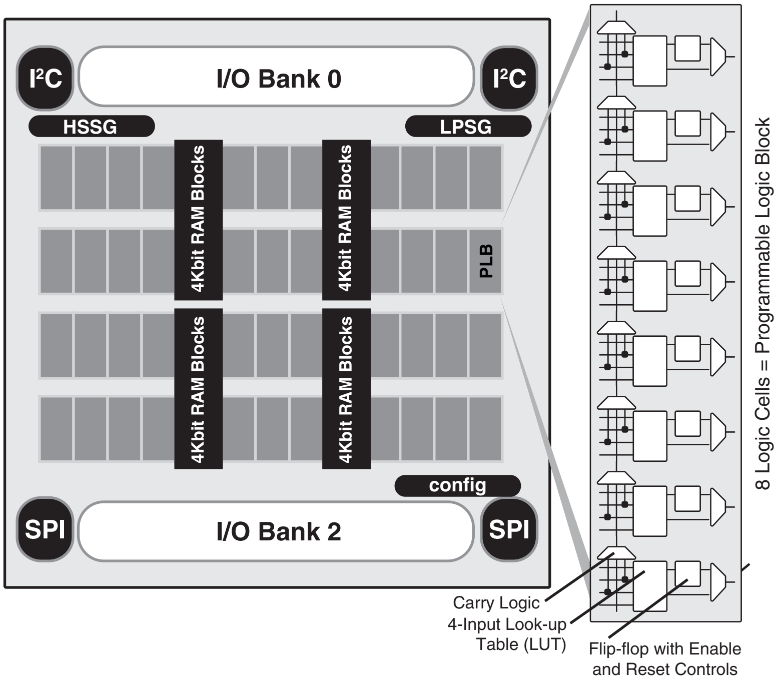
iCE40LM Family Data Sheet
Architecture

October 2013 **Advance Data Sheet DS1045**

Architecture Overview

The iCE40LM family architecture contains an array of Programmable Logic Blocks (PLB), two Strobe Generators, two user configurable I^{2}C controllers, two user configurable SPI controllers, and blocks of sysMEM™ Embedded Block RAM (EBR) surrounded by Programmable I/O (PIO). Figure 2-1shows the block diagram of the iCE40LM-4K device.

Figure 2-1. iCE40LM-4K Device, Top View



The logic blocks, Programmable Logic Blocks (PLB) and sysMEM EBR blocks, are arranged in a two-dimensional grid with rows and columns. Each column has either logic blocks or EBR blocks. The PIO cells are located at the top and bottom of the device, arranged in banks. The PLB contains the building blocks for logic, arithmetic, and register functions. The PIOs utilize a flexible I/O buffer referred to as a sysIO buffer that supports operation with a variety of interface standards. The blocks are connected with many vertical and horizontal routing channel resources. The place and route software tool automatically allocates these routing resources.

In the iCE40LM family, There are two sysIO banks, one on top and one on bottom. User can connect both V_{CCIO}s together, if all the I/Os are using the same voltage standard. Refer to the details in later sections of this document. The sysMEM EBRs are large 4 Kbit, dedicated fast memory blocks. These blocks can be configured as RAM, ROM or FIFO with user logic using PLBs.

Every device in the family has two user SPI ports, one of these (right side) SPI port also supports programming and configuration of the device. The iCE40LM also includes two user I^{2}C ports, and two Strobe Generators.

Routing

There are many resources provided in the iCE40LM devices to route signals individually with related control signals. The routing resources consist of switching circuitry, buffers and metal interconnect (routing) segments.

The inter-PLB connections are made with three different types of routing resources: Adjacent (spans two PLBs), x4 (spans five PLBs) and x12 (spans thirteen PLBs). The Adjacent, x4 and x12 connections provide fast and efficient connections in the diagonal, horizontal and vertical directions.

The design tool takes the output of the synthesis tool and places and routes the design.

Clock/Control Distribution Network

Each iCE40LM device has six global inputs, two pins on the top bank and four pins on the bottom bank

These global inputs can be used as high fanout nets, clock, reset or enable signals. The dedicated global pins are identified as Gxx and the global buffers are identified as GBUF[7:0]. These six inputs may be used as general purpose I/O if they are not used to drive the clock nets.

Table 2-2 lists the connections between a specific global buffer and the inputs on a PLB. All global buffers optionally connect to the PLB CLK input. Any four of the eight global buffers can drive logic inputs to a PLB. Even-numbered global buffers optionally drive the Set/Reset input to a PLB. Similarly, odd-numbered buffers optionally drive the PLB clock-enable input. GBUF[7:6, 3:0] can connect directly to G[7:6, 3:0] pins respectively. GBUF4 and GBUF5 can connect to the two on-chip Strobe Generators (GBUF4 connects to LPSG, GBUF5 connects to HSSG).

Table 2-2. Global Buffer (GBUF) Connections to Programmable Logic Blocks

Global Buffer	LUT Inputs	Clock	Clock Enable	Reset
GBUF0	Yes, any 4 of 8 GBUF Inputs	✓	✓	
GBUF1		✓		✓
GBUF2		✓	✓	
GBUF3		✓		✓
GBUF4		✓	✓	
GBUF5		✓		✓
GBUF6		✓	✓	
GBUF7		✓		✓

The maximum frequency for the global buffers are shown in the iCE40LM External Switching Characteristics tables later in this document.

Global Hi-Z Control

The global high-impedance control signal, GHIZ, connects to all I/O pins on the iCE40LM device. This GHIZ signal is automatically asserted throughout the configuration process, forcing all user I/O pins into their high-impedance state.

Global Reset Control

The global reset control signal connects to all PLB and PIO flip-flops on the iCE40LM device. The global reset signal is automatically asserted throughout the configuration process, forcing all flip-flops to their defined wake-up state. For PLB flip-flops, the wake-up state is always reset, regardless of the PLB flip-flop primitive used in the application.

sysCLOCK Phase Locked Loops (PLLs) - *NOT SUPPORTED on the 25-Pin WLCSP*

The sysCLOCK PLLs provide the ability to synthesize clock frequencies. The iCE40LM devices have one sysCLOCK PLL (Please note that the 25-pin WLCSP package does not support the PLL). REFERENCECLK is the reference frequency input to the PLL and its source can come from an external I/O pin, the internal strobe generator or from internal routing. EXTFEEDBACK is the feedback signal to the PLL which can come from internal routing or an external I/O pin. The feedback divider is used to multiply the reference frequency and thus synthesize a higher frequency clock output.

The PLLOUT output has an output divider, thus allowing the PLL to generate different frequencies for each output. The output divider can have a value from 1 to 64 (in increments of 2X). The PLLOUT outputs can all be used to drive the iCE40 global clock network directly or general purpose routing resources can be used.

The LOCK signal is asserted when the PLL determines it has achieved lock and de-asserted if a loss of lock is detected. A block diagram of the PLL is shown in Figure 2-3.

The timing of the device registers can be optimized by programming a phase shift into the PLLOUT output clock which will advance or delay the output clock with reference to the REFERENCECLK clock. This phase shift can be either programmed during configuration or can be adjusted dynamically. In dynamic mode, the PLL may lose lock after a phase adjustment on the output used as the feedback source and not relock until the tLOCK parameter has been satisfied.

The iCE40LM PLL functions the same as the PLLs in the iCE40 family. For more details on the PLL, see TN1251, iCE40 sysCLOCK PLL Design and Usage Guide.

Figure 2-3. PLL Diagram

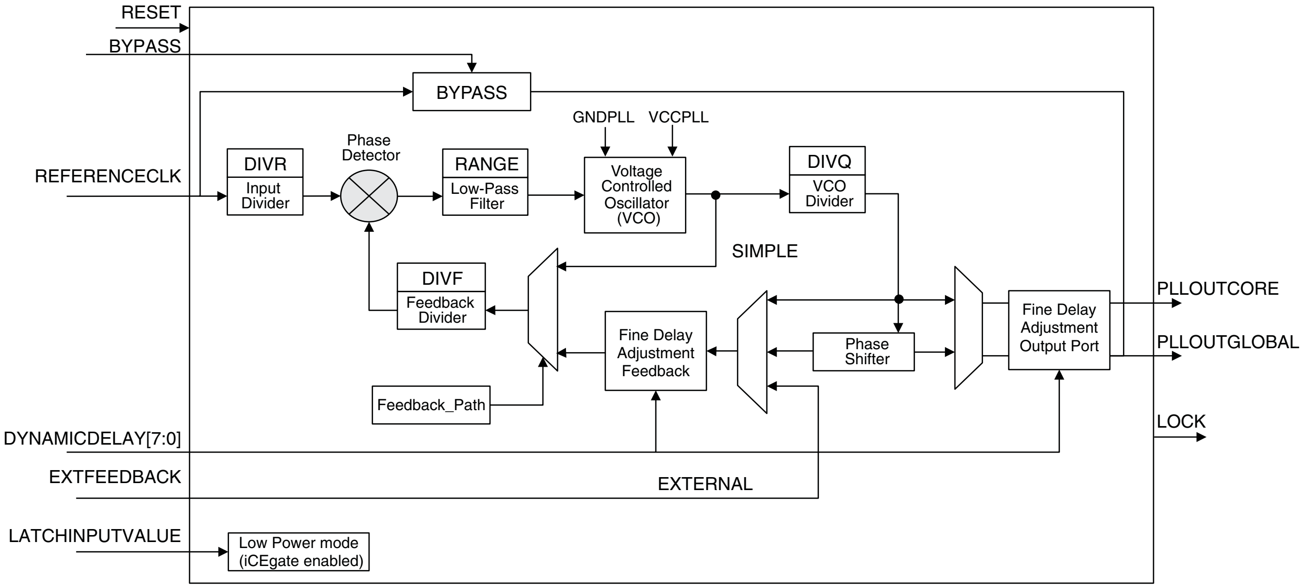


Table 2-3 provides signal descriptions of the PLL block.

Table 2-3. PLL Signal Descriptions

Signal Name	Direction	Description
REFERENCECLK	Input	Input reference clock
BYPASS	Input	The BYPASS control selects which clock signal connects to the PLLOUT output. 0 = PLL generated signal 1 = REFERENCECLK
EXTFEEDBACK	Input	External feedback input to PLL. Enabled when the FEEDBACK_PATH attribute is set to EXTERNAL.
DYNAMICDELAY[7:0]	Input	Fine delay adjustment control inputs. Enabled when DELAY_ADJUSTMENT_MODE is set to DYNAMIC.
LATCHINPUTVALUE	Input	When enabled, forces the PLL into low-power mode; PLL output is held static at the last input clock value. Set ENABLE ICEGATE_PORTA and PORTB to '1' to enable.
PLLOUTGLOBAL	Output	Output from the Phase-Locked Loop (PLL). Drives a global clock network on the FPGA. The port has optimal connections to global clock buffers GBUF4 and GBUF5.
PLLOUTCORE	Output	Output clock generated by the PLL, drives regular FPGA routing. The frequency generated on this output is the same as the frequency of the clock signal generated on the PLLOUTLGOBAL port.
LOCK	Output	When High, indicates that the PLL output is phase aligned or locked to the input reference clock.
RESET	Input	Active low reset.

sysMEM Embedded Block RAM Memory

Larger iCE40LM device includes multiple high-speed synchronous sysMEM Embedded Block RAMs (EBRs), each 4 Kbit in size. This memory can be used for a wide variety of purposes including data buffering, and FIFO.

sysMEM Memory Block

The sysMEM block can implement single port, pseudo dual port, or FIFO memories with programmable logic resources. Each block can be used in a variety of depths and widths as shown in Table 2-4.

Table 2-4. sysMEM Block Configurations[1]

Block RAM Configuration	Block RAM Configuration and Size	WADDR Port Size (Bits)	WDATA Port Size (Bits)	RADDR Port Size (Bits)	RDATA Port Size (Bits)	MASK Port Size (Bits)
SB_RAM256x16 SB_RAM256x16NR SB_RAM256x16NW SB_RAM256x16NRNW	256x16 (4K)	8 [7:0]	16 [15:0]	8 [7:0]	16 [15:0]	16 [15:0]
SB_RAM512x8 SB_RAM512x8NR SB_RAM512x8NW SB_RAM512x8NRNW	512x8 (4K)	9 [8:0]	8 [7:0]	9 [8:0]	8 [7:0]	No Mask Port
SB_RAM1024x4 SB_RAM1024x4NR SB_RAM1024x4NW SB_RAM1024x4NRNW	1024x4 (4K)	10 [9:0]	4 [3:0]	10 [9:0]	4 [3:0]	No Mask Port
SB_RAM2048x2 SB_RAM2048x2NR SB_RAM2048x2NW SB_RAM2048x2NRNW	2048x2 (4K)	11 [10:0]	2 [1:0]	11 [10:0]	2 [1:0]	No Mask Port

1. For iCE40LM EBR primitives with a negative-edged Read or Write clock, the base primitive name is appended with a 'N' and a 'R' or 'W' depending on the clock that is affected.

RAM Initialization and ROM Operation

If desired, the contents of the RAM can be pre-loaded during device configuration.

By preloading the RAM block during the chip configuration cycle and disabling the write controls, the sysMEM block can also be utilized as a ROM.

Memory Cascading

Larger and deeper blocks of RAM can be created using multiple EBR sysMEM Blocks.

RAM4k Block

Figure 2-4 shows the 256x16 memory configurations and their input/output names. In all the sysMEM RAM modes, the input data and addresses for the ports are registered at the input of the memory array.

Figure 2-4. sysMEM Memory Primitives

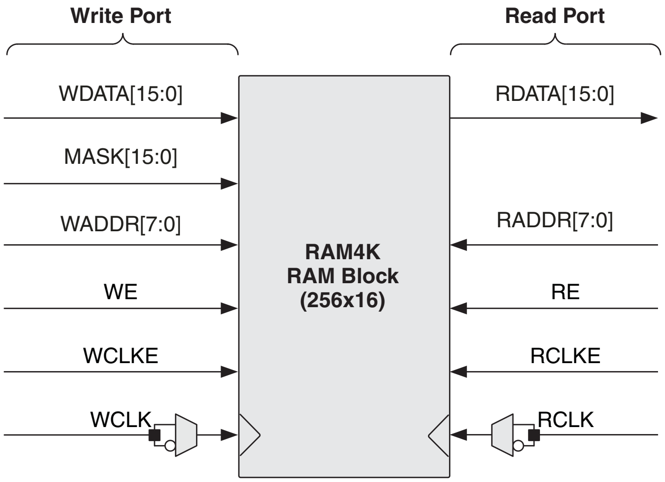


Table 2-5. EBR Signal Descriptions

Signal Name	Direction	Description
WDATA[15:0]	Input	Write Data input.
MASK[15:0]	Input	Masks write operations for individual data bit-lines. 0 = write bit; 1 = don't write bit
WADDR[7:0]	Input	Write Address input. Selects one of 256 possible RAM locations.
WE	Input	Write Enable input.
WCLKE	Input	Write Clock Enable input.
WCLK	Input	Write Clock input. Default rising-edge, but with falling-edge option.
RDATA[15:0]	Output	Read Data output.
RADDR[7:0]	Input	Read Address input. Selects one of 256 possible RAM locations.
RE	Input	Read Enable input.
RCLKE	Input	Read Clock Enable input.
RCLK	Input	Read Clock input. Default rising-edge, but with falling-edge option.

The iCE40LM EBR block functions the same as EBR blocks in the iCE40 family. For further information on the sysMEM EBR block, please refer to TN1250, Memory Usage Guide for iCE40 Devices.

Typical I/O Behavior During Power-up

The internal power-on-reset (POR) signal is deactivated when V_{CC}, V_{CCIO_2} and V_{CC_SPI} (V_{CC_SPI} is connected to V_{CCIO_2} on the 25-pin WLCSP) reach the level defined in the Power-On-Reset Voltage table in the DC and Switching Characteristics section of this data sheet. After the POR signal is deactivated, the FPGA core logic becomes active. You must ensure that all V_{CCIO} banks are active with valid input logic levels to properly control the output logic states of all the I/O banks that are critical to the application. The default configuration of the I/O pins in a device prior to configuration is tri-stated with a weak pull-up to V_{CCIO}. The I/O pins maintain the pre-configuration state until V_{CC} and V_{CCIO_2} reach the defined levels. The I/Os take on the software user-configured settings only after V_{CC_SPI} reaches the level and the device performs a proper download/configuration. Unused I/Os are automatically blocked and the pull-up termination is disabled.

Supported Standards

The iCE40LM sysIO buffer supports all single-ended input and output standards. The buffer supports the LVCMOS 1.8, 2.5, and 3.3V standards. The buffer has individually configurable options for bus maintenance (weak pull-up or none).

Table 2-7 and Table 2-8 show the I/O standards (together with their supply and reference voltages) supported by the iCE40LM devices.

Table 2-7. Supported Input Standards

Input Standard	V_{CCIO} (Typical)		
	3.3V	2.5V	1.8V
Single-Ended Interfaces			
LVCMOS33	✓		
LVCMOS25		✓	
LVCMOS18			✓

Table 2-8. Supported Output Standards

Output Standard	V_{CCIO} (Typical)
Single-Ended Interfaces	
LVCMOS33	3.3
LVCMOS25	2.5
LVCMOS18	1.8

On-Chip Strobe Generators

The iCE40LM devices feature two different Strobe Generators. One is tailored for low-power operation (Low Power Strobe Generator – LPSG), and generates periodic strobes in the Microsecond (µs) ranges. The other is tailored for high speed operation (High Speed Strobe Generator – HSSG), and generates periodic strobes in the Nanosecond (ns) ranges.Add a paragraph:

The Strobe Generators (HSSG and LPSG) provide fixed periodic strobes, and these strobes can be used as a clock source. When used as a clock source, the HSSG can provide strobe frequency in the range of 5MHz - 20MHz. The LPSG can provide strobe frequency in the range of 4KHz - 20KHz.

For further information on how to use the LPSG and HSSG, please refer to TN1275, iCE40LM On-Chip Strobe Generator Usage Guide.

iCE40LM Configuration

This section describes the programming and configuration of the iCE40LM family.

Device Configuration

There are various ways to configure the Configuration RAM (CRAM) including:

- From a SPI Flash (Master SPI mode)
- System microprocessor to drive a Serial Slave SPI port (SSPI mode)

For more details on configuring the iCE40LM, please see TN1248, iCE40 Programming and Configuration.

Power Saving Options

The iCE40LM devices feature iCEGate and PLL low power mode to allow users to meet the static and dynamic power requirements of their applications. Table 2-9 describes the function of these features.

Table 2-9. iCE40LM Power Saving Features Description

Device Subsystem	Feature Description
PLL	When LATCHINPUTVALUE is enabled, forces the PLL into low-power mode; PLL output held static at last input clock value.
iCEGate	To save power, the optional iCEGate latch can selectively freeze the state of individual, non-registered inputs within an I/O bank. Registered inputs are effectively frozen by their associated clock or clock-enable control.

iCE40LM Family Data Sheet
DC and Switching Characteristics

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Absolute Maximum Ratings[1, 2, 3]

Supply Voltage V_{CC}	-0.5 to 1.42V
Output Supply Voltage V_{CCIO} and V_{CC_SPI}	-0.5 to 3.60V
PLL Power Supply, V_{CCPLL}	-0.5 to 1.3V
I/O Tri-state Voltage Applied	-0.5 to 3.60V
Dedicated Input Voltage Applied	-0.5 to 3.60V
Storage Temperature (Ambient)	-65°C to 150°C
Junction Temperature (T_J)	-55°C to 125°C

1. Stress above those listed under the “Absolute Maximum Ratings” may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.
2. Compliance with the Lattice Thermal Management document is required.
3. All voltages referenced to GND.

Recommended Operating Conditions[1]

Symbol	Parameter		Min.	Max.	Units
V_{CC}[1]	Core Supply Voltage		1.14	1.26	V
V_{CCIO}[1, 2, 3]	I/O Driver Supply Voltage	V_{CCIO_0}, V_{CCIO_2}	1.71	3.46	V
V_{CCPLL}[4]	PLL Power Supply Voltage		1.14	1.26	V
V_{CC_SPI}[5]	Config SPI port Power Supply Voltage		1.71	3.46	V
t_{JIND}	Junction Temperature Industrial Operation		-40	100	°C

1. Like power supplies must be tied together. V_{CC} to V_{CCPLL}, V_{CCIO_0} to V_{CCIO_2} if they are at same supply voltage.
2. See recommended voltages by I/O standard in subsequent table.
3. V_{CCIO} pins of unused I/O banks should be connected to the V_{CC} power supply on boards.
4. For 25-pin WLCSP, PLL is not supported.
5. For 25-pin WLCSP, V_{CC_SPI} is connected to V_{CCIO_2} on the package. For all other packages, V_{CC_SPI} is used to power the SPI1 ports in both configuration mode and user mode.

Power Supply Ramp Rates[1]

Symbol	Parameter	Min.	Max.	Units
t_{RAMP}	Power supply ramp rates for all power supplies.	0.6	10	V/ms

1. Assumes monotonic ramp rates.

Power-On-Reset Voltage Levels[1]

Symbol	Parameter		Min.	Max.	Units
V_{PORUP}	Power-On-Reset ramp-up trip point (circuit monitoring V_{CC}, V_{CCIO_2} and V_{CC_SPI})	V_{CC}	0.64	0.99	V
		V_{CCIO_2}, V_{CC_SPI}	0.70	1.59	V
V_{PORDN}	Power-On-Reset ramp-down trip point (circuit monitoring V_{CC}, V_{CCIO_2} and V_{CC_SPI})	V_{CC}	—	0.66	V
		V_{CCIO_2}, V_{CC_SPII}	—	1.59	V

1. These POR trip points are only provided for guidance. Device operation is only characterized for power supply voltages specified under recommended operating conditions.

Power Up Sequence

For all iCE40LM devices, it is required to have the V_{CC}/V_{CCPLL} power supply powered up before all other power supplies. The V_{CC}/V_{CCPLL} has to be higher than 0.5V before other supplies are powered from GND.

Following V_{CC}/V_{CCPLL}, V_{CCSPI} should be ramped up, followed by the remaining supplies. For 25-pin WLCSP, V_{CC_SPI} is connected to V_{CCIO_2}, and the V_{CCPLL} is internally connected for that package.

ESD Performance

Please contact Lattice Semiconductor for additional information.

DC Electrical Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
I_{IL}, I_{IH}[1, 3, 4]	Input or I/O Leakage	$0V < V_{IN} < V_{CCIO} + 0.2V$	—	—	+/-10	µA
C_1	I/O Capacitance[2]	$V_{CCIO} = 3.3V, 2.5V, 1.8V$ V_{CC} = Typ., $V_{IO} = 0$ to $V_{CCIO} + 0.2V$	—	6	—	pf
C_2	Global Input Buffer Capacitance[2]	$V_{CCIO} = 3.3V, 2.5V, 1.8V$ V_{CC} = Typ., $V_{IO} = 0$ to $V_{CCIO} + 0.2V$	—	6	—	pf
V_{HYST}	Input Hysteresis	$V_{CCIO} = 1.8V, 2.5V, 3.3V$	—	200	—	mV
I_{PU}	Internal PIO Pull-up Current	$V_{CCIO} = 1.8V, 0 =< V_{IN} <= 0.65\ V_{CCIO}$	-3	—	-31	µA
		$V_{CCIO} = 2.5V, 0 =< V_{IN} <= 0.65\ V_{CCIO}$	-8	—	-72	µA
		$V_{CCIO} = 3.3V, 0 =< V_{IN} <= 0.65\ V_{CCIO}$	-11	—	-128	µA

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tri-stated. It is not measured with the output driver active. Internal pull-up resistors are disabled.
2. T_J 25°C, f = 1.0 MHz.
3. Please refer to V_{IL} and V_{IH} in the sysIO Single-Ended DC Electrical Characteristics table of this document.
4. Some products are clamped to a diode when V_{IN} is larger than V_{CCIO}.

Supply Current [1, 2, 3, 4]

Symbol	Parameter	Typ. VCC[4]	Units
$I_{CCSTDBY}$	Core Power Supply Static Current	100	µA
$I_{CCPLLSTDBY}$	PLL Power Supply Static Current		µA
$I_{CCIOSTDBY}$, $I_{CC\_SPISTDBY}$	V_{CCIO}, V_{CC_SPI} Power Supply Static Current		µA
I_{CCPEAK}	Core Power Supply Startup Peak Current		µA
$I_{CCPLLPEAK}$	PLL Power Supply Startup Peak Current		µA
$I_{CCIOPEAK}$, $I_{CC\_SPIPEAK}$	V_{CCIO}, V_{CC_SPI} Power Supply Startup Peak Current		µA

1. Assumes blank pattern with the following characteristics: all outputs are tri-stated, all inputs are configured as LVCMOS and held at V_{CCIO} or GND, on-chip PLL is off. For more detail with your specific design, use the Power Calculator tool. Power specified with master SPI configuration mode. Other modes may be up to 25% higher.
2. Frequency = 0 MHz.
3. TJ = 25°C, power supplies at nominal voltage.
4. Does not include pull-up.
5. For 25-pin WLCSP, V_{CCPLL} is tied internally on the package, and V_{CC_SPI} is also connected to $V_{CCIO\_}2$ on the package.

User I^{2}C Specifications

Parameter Symbol	Parameter Description	spec (STD Mode)			spec (FAST Mode)			Units
		Min	Typ	Max	Min	Typ	Max	
f_{SCL}	Maximum SCL clock frequency	—	—	100	—	—	400	KHz
t_{HI}	SCL clock HIGH Time	4	—	—	0.6	—	—	us
t_{LO}	SCL clock LOW Time	4.7	—	—	1.3	—	—	us
$t_{SU,DAT}$	Setup time (DATA)	250	—	—	100	—	—	ns
$t_{HD,DAT}$	Hold time (DATA)	0	—	—	0	—	—	ns
$t_{SU,STA}$	Setup time (START condition)	4.7	—	—	0.6	—	—	us
$t_{HD,STA}$	Hold time (START condition)	4	—	—	0.6	—	—	us
$t_{SU,STO}$	Setup time (STOP condition)	4	—	—	0.6	—	—	us
t_{BUF}	Bus free time between STOP and START	4.7	—	—	1.3	—	—	us
$t_{CO,DAT}$	SCL LOW to DATAOUT valid	—	—	3.4	—	—	0.9	us

User SPI Specifications

Parameter Symbol	Parameter Description	Min	Typ	Max	Units
f_{MAX}	Maximum SCK clock frequency	—	—	45	MHz
t_{HI}	HIGH period of SCK clock	9	—	—	ns
t_{LO}	LOW period of SCK clock	9	—	—	ns
$t_{SUmaster}$	Setup time (master mode)	2	—	—	ns
$t_{HOLDmaster}$	Hold time (master mode)	5	—	—	ns
$t_{SUslave}$	Setup time (slave mode)	2	—	—	ns
$t_{HOLDslave}$	Hold time (slave mode)	5	—	—	ns
$t_{SCK2OUT}$	SCK to out (slave mode)	—	—	13.5	ns

sysIO Recommended Operating Conditions

Standard	V_{CCIO} (V)		
	Min.	Typ.	Max.
LVCMOS 3.3	3.14	3.3	3.46
LVCMOS 2.5	2.37	2.5	2.62
LVCMOS 1.8	1.71	1.8	1.89

sysIO Single-Ended DC Electrical Characteristics

Input/ Output Standard	V_{IL}		V_{IH}[1]		V_{OL} Max. (V)	V_{OH} Min. (V)	I_{OL} Max. (mA)	I_{OH} Max. (mA)
	Min. (V)	Max. (V)	Min. (V)	Max. (V)				
LVCMOS 3.3	-0.3	0.8	2.0	V_{CCIO} + 0.2V	0.4	V_{CCIO} - 0.5	8	-8
					0.2	V_{CCIO} - 0.2	0.1	-0.1
LVCMOS 2.5	-0.3	0.7	1.7	V_{CCIO} + 0.2V	0.4	V_{CCIO} - 0.5	6	-6
					0.2	V_{CCIO} - 0.2	0.1	-0.1
LVCMOS 1.8	-0.3	0.35V_{CCIO}	0.65V_{CCIO}	V_{CCIO} + 0.2V	0.4	V_{CCIO} - 0.4	4	-4
					0.2	V_{CCIO} - 0.2	0.1	-0.1

1. Some products are clamped to a diode when V_{IN} is larger than V_{CCIO}.

Typical Building Block Function Performance[1, 2]

Pin-to-Pin Performance (LVCMOS25)

Function	Timing	Units
Basic Functions		
16-bit decoder	16.5	ns
4:1 MUX	18.0	ns
16:1 MUX	19.5	ns

Register-to-Register Performance

Function	Timing	Units
Basic Functions		
16:1 MUX	110	MHz
16-bit adder	100	MHz
16-bit counter	100	MHz
64-bit counter	40	MHz
Embedded Memory Functions		
256x16 Pseudo-Dual Port RAM	150	MHz

1. The above timing numbers are generated using the iCECube2 design tool. Exact performance may vary with device and tool version. The tool uses internal parameters that have been characterized but are not tested on every device.
2. Using a V_{CC} of 1.14V at Junction Temp 85C.

Derating Logic Timing

Logic timing provided in the following sections of the data sheet and the Lattice design tools are worst case numbers in the operating range. Actual delays may be much faster. Lattice design tools can provide logic timing numbers at a particular temperature and voltage.

Maximum sysIO Buffer Performance[1]

I/O Standard	Max. Speed	Units
Inputs		
LVCMOS33		MHz
LVCMOS25		MHz
LVCMOS18		MHz
Outputs		
LVCMOS33		MHz
LVCMOS25		MHz
LVCMOS18		MHz

1. Measured with a toggling pattern

iCE40LM Family Timing Adders

Over Recommended Commercial Operating Conditions[1, 2, 3]

Buffer Type	Description	Timing	Units
Input Adjusters			
LVCMOS33	LVCMOS, V_{CCIO} = 3.3V	0.18	nS
LVCMOS25	LVCMOS, V_{CCIO} = 2.5V	0.00	nS
LVCMOS18	LVCMOS, V_{CCIO} = 1.8V	0.19	nS
Output Adjusters			
LVCMOS33	LVCMOS, V_{CCIO} = 3.3V	-0.12	nS
LVCMOS25	LVCMOS, V_{CCIO} = 2.5V	0.00	nS
LVCMOS18	LVCMOS, V_{CCIO} = 1.8V	1.32	nS

1. Timing adders are relative to LVCMOS25 and characterized but not tested on every device.
2. LVCMOS timing measured with the load specified in Switching Test Condition table.
3. Commercial timing numbers are shown.

sysCLOCK PLL Timing – Preliminary

Over Recommended Operating Conditions

Parameter	Descriptions	Conditions	Min.	Max.	Units
f_{IN}	Input Clock Frequency (REFERENCECLK, EXTFEEDBACK)		TBD	TBD	MHz
f_{OUT}	Output Clock Frequency (PLLOUT)		TBD	TBD	MHz
f_{VCO}	PLL VCO Frequency		TBD	TBD	MHz
f_{PFD}	Phase Detector Input Frequency		TBD	TBD	MHz
AC Characteristics					
t_{DT}	Output Clock Duty Cycle			TBD	%
t_{PH}	Output Phase Accuracy		—	TBD	deg
t_{OPJIT}[1, 5]	Output Clock Period Jitter	f_{OUT} <= 100 MHz	—	TBD	ps p-p
		f_{OUT} > 100 MHz	—	TBD	UIPP
	Output Clock Cycle-to-cycle Jitter	f_{OUT} <= 100 MHz	—	TBD	ps p-p
		f_{OUT} > 100 MHz	—	TBD	UIPP
	Output Clock Phase Jitter	f_{PFD} <= 25 MHz	—	TBD	ps p-p
		f_{PFD} > 25 MHz	—	TBD	UIPP
t_W	Output Clock Pulse Width	At 90% or 10%		TBD	ns
t_{LOCK}[2, 3]	PLL Lock-in Time		—	TBD	us
t_{UNLOCK}	PLL Unlock Time		—	TBD	ns
t_{IPJIT}[4]	Input Clock Period Jitter	$f_{PFD} \geq 20$ MHz	—	TBD	ps p-p
		$f_{PFD} < 20$ MHz	—	TBD	UIPP
t_{FDTAP}	Fine Delay adjustment, per Tap		—	TBD	ps
t_{STABLE}[3]	LATCHINPUTVALUE LOW to PLL Stable		—	TBD	ns
t_{STABLE_PW}[3]	LATCHINPUTVALUE Pulse Width		—	TBD	ns
t_{RST}	RESET Pulse Width		TBD	TBD	ns
t_{RSTREC}	RESET Recovery Time		TBD	TBD	ns
$t_{DYNAMIC\_WD}$	DYNAMICDELAY Pulse Width		TBD	TBD	VCO Cycles

1. Period jitter sample is taken over 10,000 samples of the primary PLL output with a clean reference clock. Cycle-to-cycle jitter is taken over 1000 cycles. Phase jitter is taken over 2000 cycles. All values per JESD65B.
2. Output clock is valid after t_{LOCK} for PLL reset and dynamic delay adjustment.
3. At minimum f_{PFD}. As the f_{PFD} increases the time will decrease to approximately 60% the value listed.
4. Maximum limit to prevent PLL unlock from occurring. Does not imply the PLL will operate within the output specifications listed in this table.
5. The jitter values will increase with loading of the PLD fabric and in the presence of SSO noise.

SPI Master Configuration Time[1]

Symbol	Parameter	Conditions	Max.	Units
t_{CONFIG}	POR/CRESET_B to Device I/O Active	All devices - Low Frequency (Default)	70	ms
		All devices - Medium frequency	35	ms
		All devices - High frequency	18	ms

1. Assumes sysMEM Block is initialized to an all zero pattern if they are used.

sysCONFIG Port Timing Specifications

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
All Configuration Modes						
t_{CRESET_B}	Minimum CRESET_B LOW pulse width required to restart configuration, from falling edge to rising edge		200	—	—	ns
t_{DONE_IO}	Number of configuration clock cycles after CDONE goes HIGH before the PIO pins are activated		49	—	—	Cycles
Slave SPI						
t_{CR_SCK}	Minimum time from a rising edge on CRESET_B until the first SPI WRITE operation, first SPI_XCK clock. During this time, the iCE40LM device is clearing its internal configuration memory		1200	—	—	us
f_{MAX}	CCLK clock frequency	Write	1	—	25	MHz
		Read[1]	—	15	—	MHz
t_{CCLKH}	CCLK clock pulsewidth HIGH		20	—	—	ns
t_{CCLKL}	CCLK clock pulsewidth LOW		20	—	—	ns
t_{STSU}	CCLK setup time		12	—	—	ns
t_{STH}	CCLK hold time		12	—	—	ns
t_{STCO}	CCLK falling edge to valid output		13	—	—	ns
Master SPI						
f_{MCLK}	MCLK clock frequency	Low Frequency (Default)	6			MHz
		Medium Frequency[2]	18			MHz
		High Frequency[2]	31			MHz
t_{MCLK}	CRESET_B HIGH to first MCLK edge		1200	—	—	us

1. Supported with 1.2V Vcc and at 25C.
2. Extended range f_{MAX} Write operation support up to 53MHz with 1.2V V_{CC} and at 25C.

iCE40LM Family Data Sheet
Pinout Information

October 2013 **Advance Data Sheet DS1045**

Signal Descriptions

Signal Name	Function	I/O	Description
Power Supplies			
V_{CC}	Power	-	Core Power Supply
V_{CCIO_0}	Power	-	Power Supply for I/Os in Bank 0
V_{CCIO_2}	Power	-	Power Supply for I/Os in Bank 2
V_{CC_SPI}	Power	-	Power supply for SPI1 ports. For 25-pin WLCSP, this signal is connected to V_{CCIO_2}
V_{CCPLL}	Power	-	Power supply for PLL. For 25-pin WLCSP, this is connected internally to V_{CC}
GND/GNDPLL	GROUND	-	Ground
Dedicated Configuration Signals			
CRESET	Configuration	I	Configuration Reset, active LOW. No internal pull-up resistor. Either actively driven externally or connect an 10K-ohm pull-up resistor to V_{CCIO_2}.
CDONE	Configuration	I/O	Configuration Done. Includes a weak pull-up resistor to VCCIO_2.
SPI and Config SPI Ports			
SPI1_SCK/PIO[T/B]_x[HD]	User SPI1	I/O	In user mode, used as CLK signal on SPI interface for sensor management function.
	Configuration	I/O	This pins is shared with device configuration. During configuration, this pin is CLK signal connecting to external SPI memory
	General I/O	I/O	In user mode, when the SPI interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
SPI1_MISO/PIO[T/B]_x[HD]	User SPI1	I/O	In user mode, used as Input (Master Mode) or Output (Slave Mode) signal on SPI interface for sensor management function.
	Configuration	I/O	This pins is shared with device configuration. During configuration, this pin is Input signal connecting to external SPI memory.
	General I/O	I/O	In user mode, when the SPI interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
SPI1_MOSI/PIO[T/B]_x[HD]	User SPI1	I/O	In user mode, used as Output (Master Mode) or Input (Slave Mode) signal on SPI interface for sensor management function.
	Configuration	I/O	This pins is shared with device configuration. During configuration, this pin is Output signal connecting to external SPI memory.
	General I/O	I/O	In user mode, when the SPI interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O

Signal Name	Function	I/O	Description
SPI1_CSN/PIO[T/B]_x[HD]	User SPI1	I/O	In user mode, used as CSN signal on SPI interface for sensor management function. This pin is output pin in Master Mode, and input in in Slave Mode.
	Configuration	I/O	This pins is shared with device configuration. During configuration, this pin is CSN signal connecting to external SPI memory
	General I/O	I/O	In user mode, when the SPI interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
SPI2_SCK/PIO[T/B]_x[HD]	User SPI2	I/O	In user mode, used as CLK signal on SPI interface for sensor management function.
	General I/O	I/O	In user mode, when the SPI interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
SPI2_MISO/PIO[T/B]_x[HD]	User SPI2	I/O	In user mode, used as Input (Master Mode) or Output (Slave Mode) signal on SPI interface for sensor management function.
	General I/O	I/O	In user mode, when the SPI interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
SPI2_MOSI/PIO[T/B]_x[HD]	User SPI2	I/O	In user mode, used as Output (Master Mode) or Input (Slave Mode) signal on SPI interface for sensor management function.
	General I/O	I/O	In user mode, when the SPI interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
SPI2_CSN/PIO[T/B]_x[HD]	User SPI2	I/O	In user mode, used as CSN signal on SPI interface for sensor management function. This pin is output pin in Master Mode, and input in in Slave Mode.
	General I/O	I/O	In user mode, when the SPI interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
I^{2}C Ports			
I2C1_SCL/PIO[T/B]_x[HD]	User I2C1	I/O	Used as CLK signal on I^{2}C interface for sensor management function.
	General I/O	I/O	When the I^{2}C interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
I2C1_SDA/PIO[T/B]_x[HD]	User I2C1	I/O	Used as Data signal on I^{2}C interface for sensor management function.
	General I/O	I/O	When the I^{2}C interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O

Signal Name	Function	I/O	Description
I2C2_SCL/PIO[T/B]_x[HD]	User I2C2	I/O	Used as CLK signal on I^{2}C interface for sensor management function.
	General I/O	I/O	When the I^{2}C interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
I2C2_SDA/PIO[T/B]_x[HD]	User I2C2	I/O	Used as Data signal on I^{2}C interface for sensor management function.
	General I/O	I/O	When the I^{2}C interface is not used, user can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
Global Signals			
PIO[T/B]_x[HD]/Gn	General I/O	I/O	User can program this pin as general I/O pin for user functions. (x represents ball on the package) [T/B]: T=Vccio_0 bank, B=Vccio_2 bank. [HD]=High Drive I/O
	Global Signal	I	Global input used for high fanout, or clock/reset net. n=0,1,2,3,6,7. The Gn Global input pin can drive the corresponding GBUFn global buffer.
General Purpose I/O			
PIO[T/B]_x[HD]	General I/O	I/O	User can program this pin as general I/O pin for user functions. (x represents ball on the package)

Pin Information Summary

Pin Type		iCE40LM-1K			iCE40LM-2K			iCE40LM-4K		
		SWG25	CM36	CM49	SWG25	CM36	CM49	SWG25	CM36	CM49
General Purpose I/O Per Bank	Bank 0	7	15	20	7	15	20	7	15	20
	Bank 2[1]	11	13	17	11	13	17	11	13	17
Total General Purpose I/Os		18	28	37	18	28	37	18	28	37
Vcc		1	1	2	1	1	2	1	1	2
Vccio	Bank 0	1	1	1	1	1	1	1	1	1
	Bank 2	1	1	1	1	1	1	1	1	1
V_{CC_SPI}		0	0	1	0	0	1	0	0	1
V_{CCPLL}		0	1	1	0	1	1	0	1	1
Miscellaneous Dedicated Pins		2	2	2	2	2	2	2	2	2
GND		2	2	4	2	2	4	2	2	4
NC		0	0	0	0	0	0	0	0	0
Reserved		0	0	0	0	0	0	0	0	0
Total Balls		25	36	49	25	36	49	25	36	49
SPI Interfaces	Bank 0	0	0	0	0	0	0	0	0	0
	Bank 2	1	1	1	2	2	2	2	2	2
I^{2}C Interfaces	Bank 0	1	1	1	2	2	2	2	2	2
	Bank 2	0	0	0	0	0	0	0	0	0

1. Including General Purpose I/Os powered by V_{CC_SPI} and V_{CCPLL}.

iCE40LM Family Data Sheet
Ordering Information

September 2013 **Advance Data Sheet DS1045**

iCE40LM Part Number Description

iCE40LMXXX - XXXXXTR

Device Family
iCE40LM FPGA

Logic Cells
1K = 1,000 Logic Cells
2K = 2,000 Logic Cells
4K = 3,520 Logic Cells

TR
= Tape-and-Reel

Package
SWG25 = 25-Ball WLCSP (0.35 mm Ball Pitch)
CM36 = 36-Ball ucBGA (0.4mm Ball Pitch)
CM49 = 49-Ball ucBGA (0.4mm Ball Pitch)

All parts are shipped in tape-and-reel.

Ordering Part Numbers

Part Number	LUTs	Supply Voltage	Package	Leads	Temp.
iCE40LM1K-SWG25TR	1000	1.2V	Halogen-Free caBGA	25	IND
iCE40LM1K-CM36TR	1000	1.2V	Halogen-Free csBGA	36	IND
iCE40LM1K-CM49TR	1000	1.2V	Halogen-Free csBGA	49	IND
iCE40LM2K-SWG25TR	2000	1.2V	Halogen-Free caBGA	25	IND
iCE40LM2K-CM36TR	2000	1.2V	Halogen-Free csBGA	36	IND
iCE40LM2K-CM49TR	2000	1.2V	Halogen-Free csBGA	49	IND
iCE40LM4K-SWG25TR	3520	1.2V	Halogen-Free caBGA	25	IND
iCE40LM4K-CM36TR	3520	1.2V	Halogen-Free csBGA	36	IND
iCE40LM4K-CM49TR	3520	1.2V	Halogen-Free csBGA	49	IND

iCE40LM Family Data Sheet
Revision History

Date	Version	Section	Change Summary
August 2013	00.1 EAP	All	Initial release.
September 2013	00.2 EAP	All	General updates to all sections.
October 2013	01.0	All	General updates for product launch.
		Pinout Information	Updated ball map to 25-pin WLCSP.